









Release Date: 11 August 2024 Version: A1.1

PRODUCT DATASHEET



- ► PLCC6 SMD with IC
- ➤ 3535IC 1.47t Series
- ► Red/Green/Blue

N0M65S39IC







3535 IC-Integrated Compliant





AUTOMOTIV AEC-Q102

FEATURES:

- Package: PLCC6 STD Package with Integrated IC
- Forward Current: 20mA
- Forward Voltage (typ.): +4.5~+5.5V
- Luminous Intensity (typ.): 460/1900/330mcd*
- Colour: Red/Green/Blue
- Dominant Wavelength (typ.): 633/527/457nm
- Viewing Angle: 120°
- **Materials:**
 - Resin: Silicone (White Diffused)
- Operating Temperature: -40~+105°C
- Storage Temperature: -40~+105°C
- IC Feature: Serial data transmission signal by dual-wire DATA & CLK lines. One pixel contains R, G, and B colour that each can achieve 256 level brightness grayscales, which forms 16,777,216 combination colours. Support sleep/wake-up mode. In sleep mode, the LED current is lower than 5µA.
- Soldering methods: IR reflow soldering
- MSL Level: acc. to JEDEC J-STD-020E Level 2a
- Packing: 12mm tape with max.1300pcs/reel, ø180mm (7")

* in order of Red/Green/Blue

APPLICATIONS:

- Automotive Interior Light
- Telecommunication
- Home Appliance
- **Decoration Lighting**
- Full Colour LED Strip
- **Gaming Device**

Support sleep/wake up mode. In sleep mode the LED's current was lower than 5µA



CHARACTERISTICS:

Absolute Maximum Characteristics (Ta=25°C)

Parameter	Symbol	Ratings	Unit
IC Power Supply Voltage	V_{DD}	Max. 6.5	V
Rate of Data Signal	F _{CLK}	15	MHz
Max. LED Output Current	Іомах	20/channel	mA
Power Dissipation	P _D	Max. 400	mW
Operating Temperature	Topr	-40~+105	°C
Storage Temperature	T _{STG}	-40~+105	°C
Electrostatic Discharge (HBM) acc. To ANSI/ESDA/JEDEC JS-001	ESD	2000	V
Thermal Resistance Junction/Solder Point	RTH _{J-S}	65/110/100*	°C/W
Soldering Temperature (10s)	T _{SD}	245	°C

^{*} in order of Red/Green/Blue

Electrical & Optical Characteristics (Ta=25°C, V_{DD}=5V)

Parameter		Symbol	Values			Lloit	Test	
		Symbol	Min.	Тур.	Max.	Unit	Condition	
Forward Voltage		V _F	4.5		5.5	V		
	R		370	460	570			
Luminous Intensity	G	lv	1520	1900	2380	mcd	V _{DD} =5V	
	В		270	330	410			
	R		630		636			
Dominant Wavelength	G	$\lambda_{\sf d}$	524		529	nm	V _{DD} =5V	
	В		455		460			
Viewing Angle		2θ _{1/2}		120		deg	V _{DD} =5V	

^{1.} Tolerance of Measure: Luminous Intensity: ±10%, Dominant Wavelength: ±1.0nm, View Angle(2θ1/2): ±5%



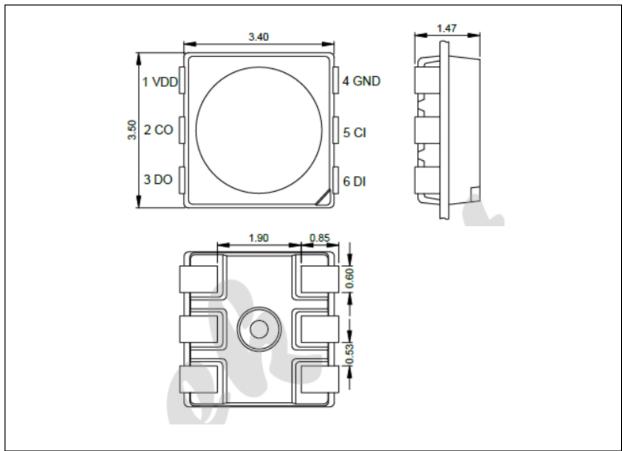
Electrical & Optical Characteristics (Ta=25°C)

Parameter	Symbol		Unit	Test		
raiailletei	Зуппоот	Min. Typ.		Max.	Offic	Condition
Supply Voltage	V_{DD}	4.5	5.0	5.5	V	
Innut Voltage Level	V _{IH}	2.7		V _{DD} +0.4	V	V _{DD} =4.0~5.5V
Input Voltage Level	VIL	-0.4		1.0	V	V _{DD} -4.0 3.3V
Clock High Level Width	Тськн	30			ns	
Clock Low Level Width	T _{CLKL}	30			ns	
Data Set-Up Time	T _{SETUP}	10			ns	
Data Hold Time	T _{HOLD}	5			ns	
Working Current (IC)	I _{DD}			2	mA	I _{out} =OFF
Static Current	I _{sleep}			5	μΑ	Sleep Mode



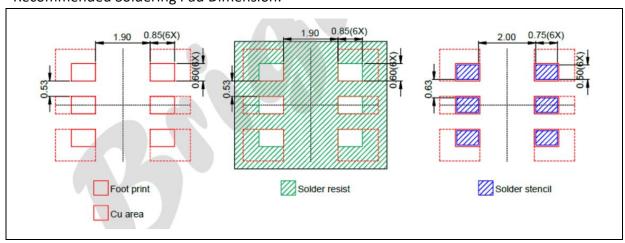
OUTLINE DIMENSION:

Package Dimension:



- 1. All dimensions are in millimetre (mm).
- 2. Tolerance ±0.2mm, unless otherwise noted.

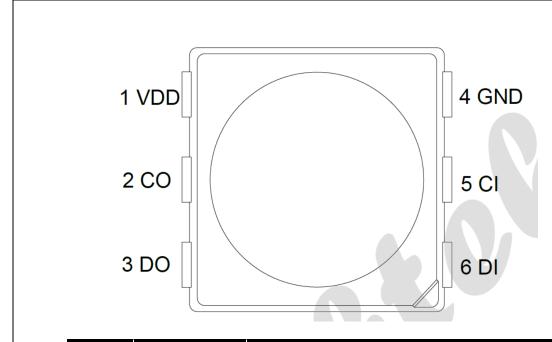
Recommended Soldering Pad Dimension:



- 1. Dimensions are in millimetre (mm).
- 2. Tolerance ±0.1mm with angle tolerance ±0.5°.



PIN CONFIGURATION:



No.	Symbol	Function Description
1	VDD	Supply Voltage
2	СО	Clock Output
3	DO	Data Output
4	GND	Ground
5	CI	Clock Input
6	DI	Data Input

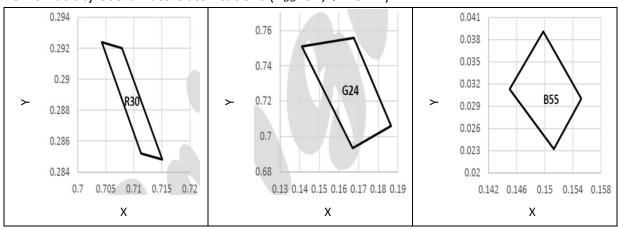


BINNING GROUPS:

Luminous Intensity Classifications (V_{DD}=5V; I_F=20mA):

Со	Code Min.		Max.	Unit	
Dod	1	370	460	mad	
Red	2	460	570	mcd	
Croon	1	1520	1900	mcd	
Green	2	1900	2380		
Dlug	1	270	330	mad	
Blue	2	330	410	mcd	

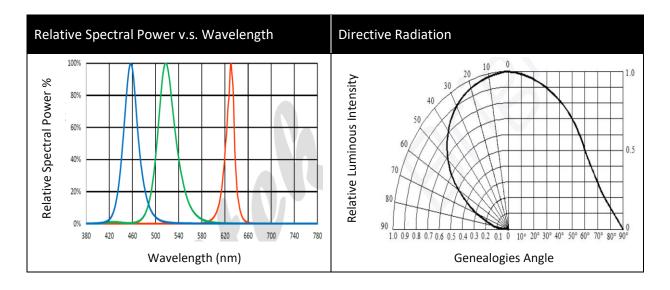
Chromaticity Coordinate Classifications (V_{DD}=5V; I_F=20mA):

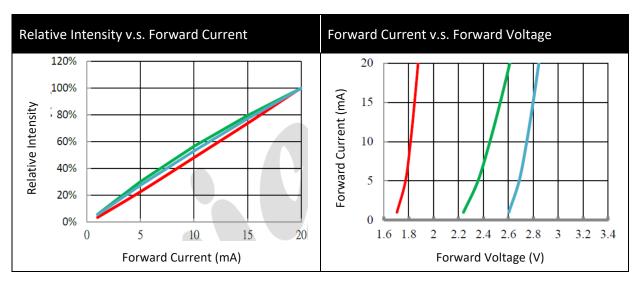


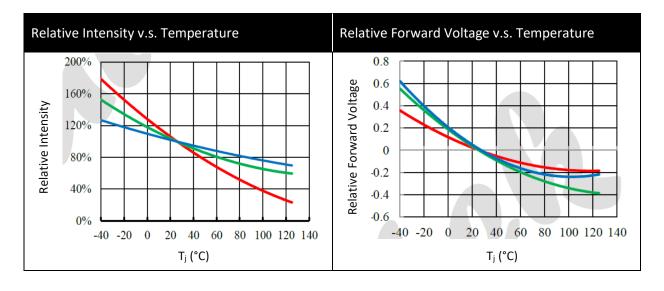
	1	1 2 3		2		4	4	
	Х	Υ	Х	Y	Х	Υ	Х	Υ
R30	0.7043	0.2924	0.7079	0.2920	0.7151	0.2848	0.7113	0.2852
G24	0.1676	0.7558	0.1411	0.7510	0.1670	0.6934	0.1866	0.7059
B55	0.1450	0.0313	0.1513	0.0232	0.1552	0.0300	0.1498	0.0391



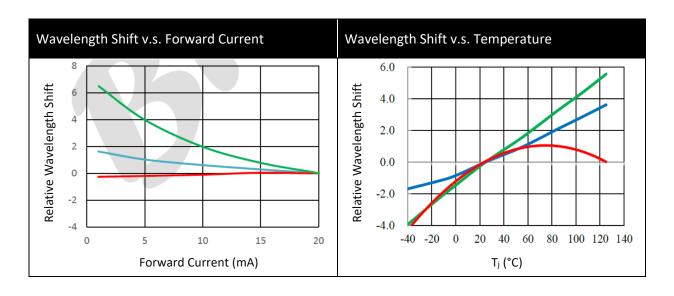
ELECTRO-OPTICAL CHARACTERISTICS (Full PWM):

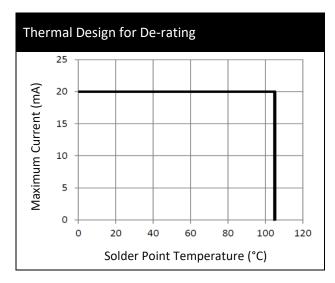








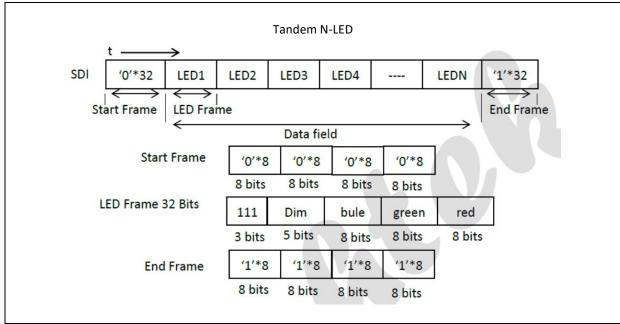






Function Description:

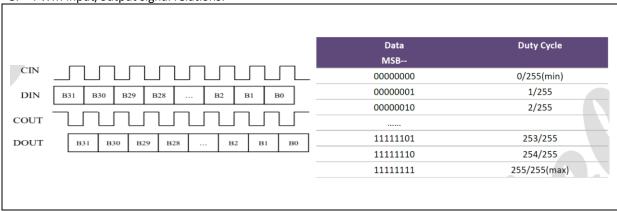
1. Series data structure:



2. Dim 5-Bit (level 32) brightness adjustment (simultaneous control of OUTR/OUTG/OUTB three port current):

Data	Driving Current
MSB←→LSB	
00000	0/31
00001	1/31
00010	2/31
11110	30/31
11111	31/31(max)

3. PWM input/output signal relations:

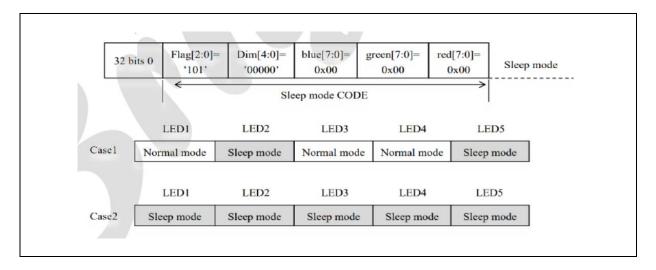




4. Sleep and power saving mode:

LED supports sleep/wake-up modes for power saving purpose. After the IC receives 24-bits 0's BGR data (that is B[7:0]=8h00, G[7:0]=8h00, R[7:0]=8h00), in the meantime, both of the data in 3-bits FLAG and 5-bits DIMMING is 8h'A0' (that is FLAG[2:0]=3b101 and DIMMING[4:0]=5b00000), the IC will entre sleep mode, its current is about 1μ A.

The IC will wake-up from sleep mode once receiving the new data with the data of FLAG[2:0], DIMMING[4:0] is not 8h'A0'; after wake-up, all sleeping circuits in IC return to normal working mode within 1ms. Since it takes 1ms for a sleeping IC to return to normal function mode, it is recommended for a host to wait for 1ms to send display data and command after issuing a wake-up command.

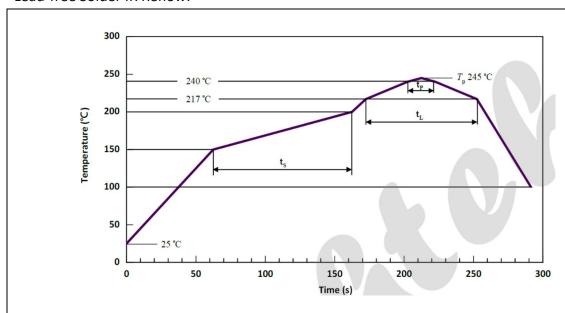


In case 1, while lamp 2 is under sleep mode, in the following data transfer process, the state of lamp 2 will be not changed as long as the 32-bits data for lamp 2 is received with data of FLAG[2:0] and DIMMING[4:0] being 8h"A0". It means lamp 2 will keep in sleep mode as well. In this situation, lamp 2 can pass through the remaining data to lamp 3 (32-bits) to change the display data of lamp 3. In other words, the sleeping chip is able to pass the data to the next chips.



RECOMMENDED SOLDERING PROFILE:

Lead-free Solder IR Reflow:



Profile Feature	Symbol	Symbol Pb-Free (SnAgCu) Assembly				
		Minimum Recommendat		Maximum		
Ramp-up Rate to Preheat			2	3	K/s	
25 °C to 150 °C			2	3	NS	
Time ts	ts	60	100	120	S	
T _{smin} to T _{smax}	ıs	00	100	120	3	
Ramp-up Rate to Peak			2	3	K/s	
T _{Smax} to T _P			2	3	ŊS	
Liquids Temperature	TL		217		°C	
Time Above Liquids Temperature	tL		80	100	S	
Peak Temperature	Tp		245	260	°C	
Time Within 5 °C of the Specified	Тр			10	_	
Peak Temperature T _P - 5 K	I P			10	S	
Ramp-Down Rate			3	4	K/s	
T _P to 100 °C			3	4	NS	
Time				480	5	
25 °C to T _P				400	5	

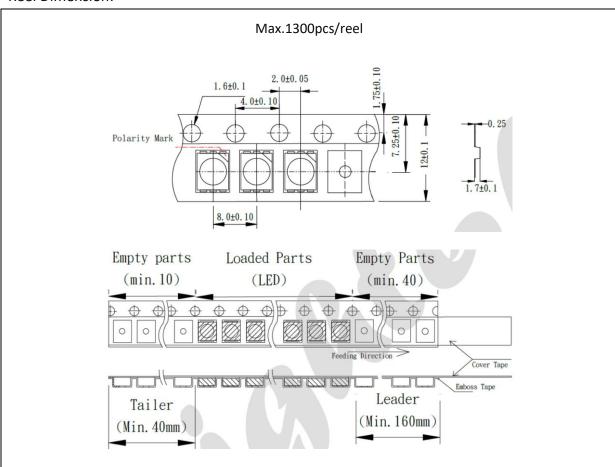
Note:

- 1. We recommend the reflow temperature 240°C (±5°C). The maximum soldering temperature should be limited to 245°C.
- 2. Maximum reflow soldering: 2 times.
- 3. Before, during, and after soldering, should not apply stress on the components and PCB board.



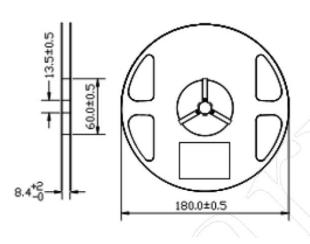
PACKING SPECIFICATION:

Reel Dimension:



Notes:

- 1. Empty component pockets are sealed with top cover tape
- 2. The cathode is oriented towards the tape sprocket hole in accordance with ANSI/EIA RS-481 specifications
- 3. The remainder packing in multiples of 500pcs.





PRECAUTIONS OF USE:

Storage:

It is recommended to store the products in the following conditions:

- Humidity: 60% R.H. Max.
- Temperature: 5°C~30°C (41°F ~86°F).

Shelf life in sealed bag: 12 months at 5°C~30°C and <60% R.H.

Once the package is opened, the products should be used within 4 weeks. Otherwise, they should be kept in a damp-proof box with descanting agent stored at R.H.<10% and apply baking before use.

Over-Current Proof:

Must apply resistors for protection otherwise slight voltage shift will cause big current change and burnout will happen.

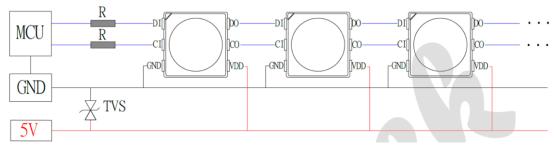
Baking:

It is recommended to bake the LED before soldering if the pack has been unsealed for longer than 24hrs. The suggested baking conditions are as followings:

• 60±3°C x 6hrs and <5%RH, taped / reel package.

It's normal to see slight color fading of carrier (light yellow) after baking in process.

Typical Application Circuit:



Circuit description:

- 1. A bypass capacitor should be connected in parallel between VDD and GND of each bead. It is recommended to use the 104 capacitor.
- 2. A $100\Omega^{\sim}300\Omega$ resistance is connected between the first lamp bead and MCU signal line to reduce the impact of MCU output signal surge voltage. It can also be replaced with a magnetic bead to enhance the interference ability.
- 3. TVS tube shall be added at the power inlet position of the LED module, and the TVS protection voltage shall be within the normal working voltage range of the LED as far as possible, so as to reduce the damage of the high voltage surge at the power end to the lamp bead.
- 4. DIN and CIN of each ICLED connect an ESD tube to GND to reduce EMC interference, and the clamping voltage of ESD tube is controlled at about 5.5V.

ESD (Electrostatic Discharge):

Static Electricity or power surge will damage the LED. Use of a conductive wrist band or anti-electrosatic glove is recommended when handing the LED all time. All devices, equipment, machinery, work tables, and storage racks must be properly grounded.



REVISION RECORD:

Version	Date	Summary of Revision
A1.0	20/07/2023	Datasheet set-up.
A1.1	11/08/2024	Revise typical application circuit drawing and description.